

Isc N-Channel MOSFET Transistor

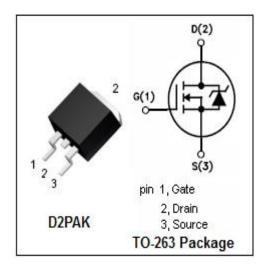
AOB260I

• FEATURES

- · With To-263(D2PAK) package
- · Low input capacitance and gate charge
- · Low gate input resistance
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



Switching applications

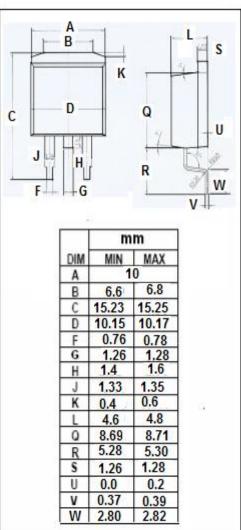


• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	60	V
V _{GSS}	Gate-Source Voltage	±20	V
I _D	Drain Current-ContinuousTc=25℃ Tc=100℃	140 110	А
I _{DM}	Drain Current-Single Pulsed	500	А
P _D	Total Dissipation @Tc=25℃	330	W
T _{ch}	Max. Operating Junction Temperature	175	$^{\circ}\mathbb{C}$
T _{stg}	Storage Temperature	-55~175	$^{\circ}$ C

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	0.45	°C/W	
Rth(ch-a)	n-a) Channel-to-ambient thermal resistance		°C/W	



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AOB2601

ELECTRICAL CHARACTERISTICS

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T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D =0.25mA	60			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} ; I _D =0.25mA	2.0		4.0	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =20A		1.7	2.2	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V;V _{DS} =0V			±0.1	μА
I _{DSS}	Drain-Source Leakage Current	V _{DS} =60V; V _{GS} = 0V;Tj=25°C V _{DS} =60V; V _{GS} = 0V;Tj=55°C			1 5	μ А
V _{SDF}	Diode forward voltage	I _{SD} =1A, V _{GS} = 0 V			1.0	V

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